

# TL0374J 0.03 – 3.0 GHz GaAs Ultra Low Noise Amplifier

**Application Note: TL0374J EVB A** 

# Application Note 1800MHz~2100MHz 5.0V 60mA

**Rev-1.1** 

Revision 1.1, 2023-11-08



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## 1. General Description

The TL0374J is a broadband, ultra-low Noise Amplifier (LNA) providing high gain and linearity. With a simple input and output match, this LNA can be tuned for different frequency bands targeting LTE (small cells and infrastructure) and any other applications requiring low noise, high gain, and linearity. For >3GHz frequency band, TL0375J can be considered. The TL0374J is packaged in a compact, low-cost Dual Flat No Lead (DFN) 2x2x0.75mm, 8 pin plastic package.

TL0374J-EVB-A is an evaluation board specially tuned for frequency range of 1800MHz~2100MHz applications. Its high gain, low noise performance makes it suitable.

### 2. TL0374J-EVB-A Board Details

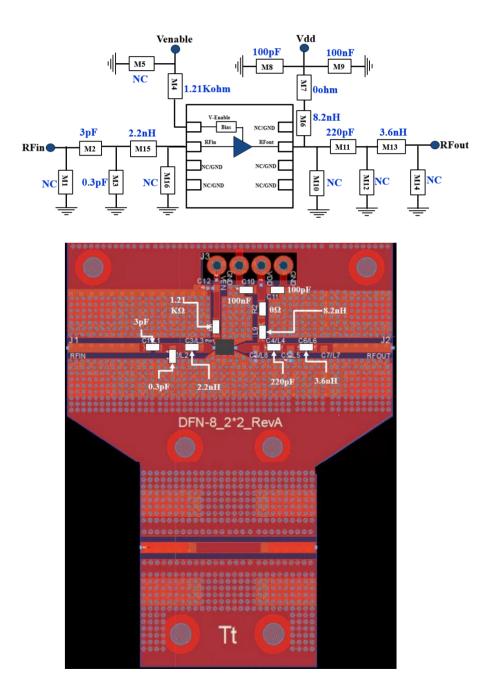


Figure 2.1 TL0374J-EVB-A 1800MHz ~ 2100MHz Schematic and EVB LayoutApplication Note: TL0374J EVB A3Revision 1.1, 2023.11.08



## 3. TL0374J-EVB-A Bill of Material

Component ID	Value	Manufacturer	Recommended Part Number	
M2	3.0pF	Murata	GJM1555C1H3R0BB01	
M3	0.3pF	Murata	GJM1555C1HR30BB01	
M15	2.2nH	Coil craft / Wurth Elektronik	0402HP-2N2XJE /744765022A	
M4	1.21KΩ	Panasonic ERJ-2RKF1211X		
M8	100pF	AVX	04025A101JAT4A	
M9	100nF	TDK	C1005X7R1H104K050BE	
M7	0Ω	Panasonic	ERJ-2GE0R00X	
M6	8.2nH	Coil craft / Wurth Elektronik 0402HP-8N2XGE /744765		
M11	220pF	Kemet C0402C221K5GACAU		
M13	3.6nH	Coil Craft / Wurth Elektronik 0402HP-3N6XGE /744765		
Q1	GaAs LNA	Tagore Technology TL0374J		
PCB		Rogers RO4350B, 20 mils, 1 oz copper		

#### Table 3.1 TL0374J-EVB-A BOM

## 4. TL0374J-EVB-A Biasing Sequence

Turn ON Device	Turn OFF Device		
1. Set Venable to +5V	1. Turn RF power off		
2. Set $V_{DD}$ to +5V	2. Turn off V <sub>DD</sub>		
3. Device will draw required IDQ current	3. Turn off Venable		
4. Apply RF power			

#### Table 4.1 TL0374J-EVB-A Bias and Sequencing

## 5. <u>TL0374J-EVB-A Board Measurement Summary</u>

Frequency (MHz)	EVB Noise figure (dB)	Gain(dB)	OP1 (dBm)	OIP3(dBm) Fspacing:1MHz 0dBm Pout/tone	S11(dB)	S22(dB)	Mu1
1800	0.4	21.9	18.7	35.0	-17	-8.9	1.2
1900	0.5	21.5	19.5	35.5	-27	-9.9	1.2
2000	0.5	21.0	18.3	35.8	-26.5	-9.6	1.2
2100	0.5	20.4	18.8	37.3	-18	-8.6	1.2

#### Table 5.1 TL0374J-EVB-A Electrical Characteristics Summary



### 6. TL0374J-EVB-A Test Results

All the tests are carried out at room temperature.

#### 6.1. S parameters

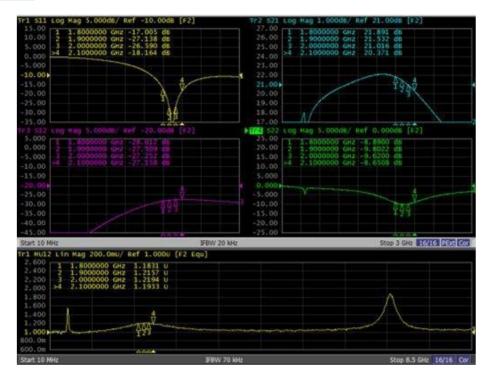


Figure 6.1.1. S parameters of TL0374J-EVB-A

#### 6.2. SMA to SMA Noise Figure

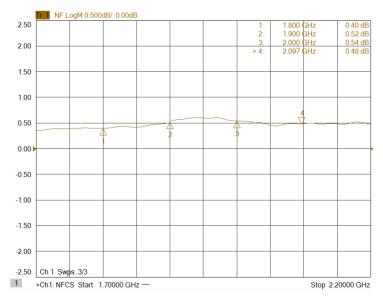
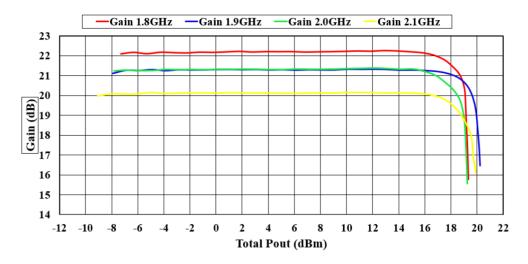


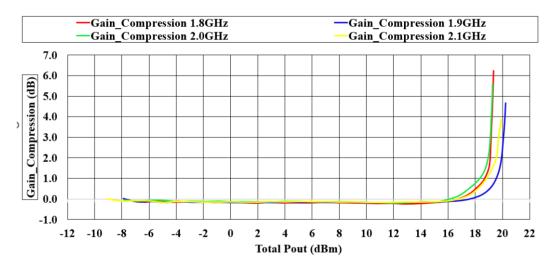
Figure 6.2.1 SMA to SMA NF of TL0374J-EVB-A



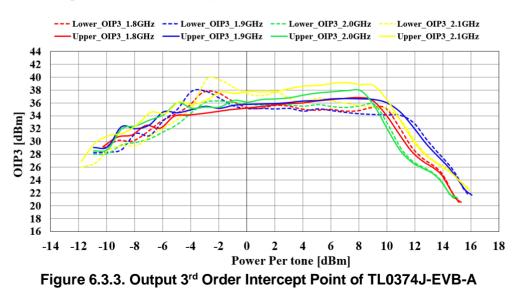
#### 6.3. Large Signal Test Results













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